74HC4050 Hex non-inverting HIGH-to-LOW level shifter Rev. 3 – 31 January 2013

Product data sheet

1. General description

The 74HC4050 is a hex buffer with over-voltage tolerant inputs. Inputs are overvoltage tolerant to 15 V which enables the device to be used in HIGH-to-LOW level shifting applications.

2. Features and benefits

- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ♦ HBM JESD22-A114F exceeds 2 000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

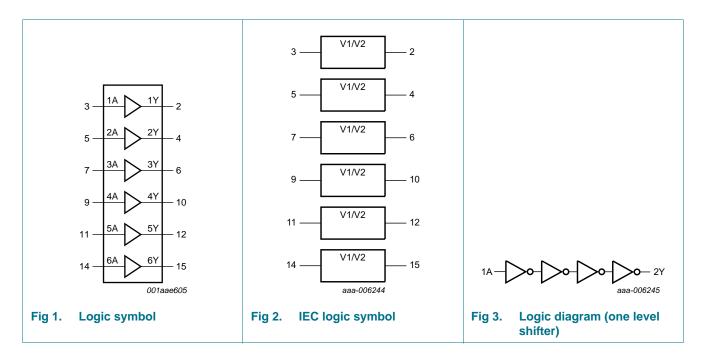
Table 1.Ordering information

Type number	Package									
	Temperature range	Name	Description	Version						
74HC4050N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4						
74HC4050D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1						
74HC4050DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1						
74HC4050PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1						



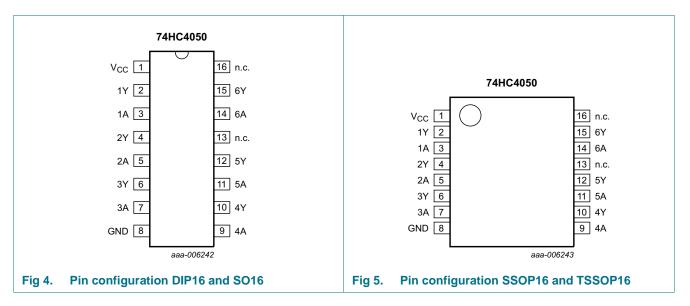
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4. Functional diagram



5. Pinning information

5.1 Pinning



Hex non-inverting HIGH-to-LOW level shifter

5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
V _{CC}	1	supply voltage
1Y to 6Y	2, 4, 6, 10, 12, 15	output
1A to 6A	3, 5, 7, 9, 11, 14	input
GND	8	ground (0 V)
n.c.	13, 16	not connected

6. Functional description

Table 3. Function table [1]	
Input	Output
nA	nY
L	L
Н	Н

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4.Limiting values

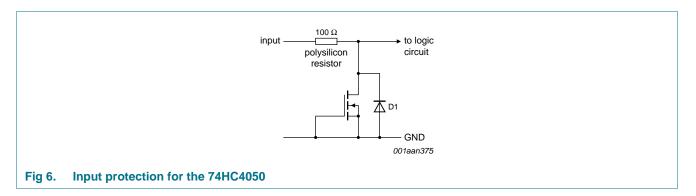
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					-
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
V _{IK}	input clamping voltage		-0.5	+16	V
I _{IK}	input clamping current	V _I < -0.5 V	-20	-	mA
I _{OK}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	$V_{O} = -0.5 \text{ V to} (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	DIP16 package	<u>[1]</u> _	750	mW
		SO16, SSOP16 and TSSOP16 packages	[2] _	500	mW

[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 $^\circ C.$

For SO16 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.
 For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	15	V
Vo	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}; \text{ V}_{I} = 2.0 \text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 4.5 \text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 6.0 \text{ V}$	-	-	83	ns/V
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 10.0 \text{ V}$	-	-	81	ns/V
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 15.0 \text{ V}$	-	-	83	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	ditions T _{amb} = 25 °C		T _{amb} = −40 °C to +85 °C		T _{amb} = −40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
V _{IH}	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.3	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.1	-	4.2	-	4.2	-	V
V _{IL} LOW-level input voltage		$V_{CC} = 2.0 V$	-	0.7	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 V$	-	1.8	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.3	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_0 = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	3.98	-	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V

Hex non-inverting HIGH-to-LOW level shifter

Symbol Parameter Conditions T_{amb} = 25 °C T_{amb} = -40 °C to T_{amb} = -40 °C to Unit +85 °C +125 °C Min Тур Max Min Max Min Max $V_{I} = V_{IH} \text{ or } V_{IL}$ VOL LOW-level output voltage $I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$ V 0.1 0.1 0.1 ---- $I_0 = 20 \ \mu A; V_{CC} = 4.5 \ V$ 0.1 0.1 0.1 V ---- $I_0 = 20 \ \mu A; V_{CC} = 6.0 \ V$ --0.1 -0.1 _ 0.1 V $I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ 0.26 0.33 0.4 V ---- $I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$ 0.26 0.33 0.4 V ---- $V_I = V_{CC}$ or GND; Ιı input leakage μΑ -±0.1 _ ± 1.0 ± 1.0 -- $V_{CC} = 6.0 V$ current $V_{I} = 15 \text{ V}; V_{CC} = 2.0 \text{ V} \text{ to}$ ±5.0 ±5.0 --±0.5 -μΑ 6.0 V $V_{I} = 15 \text{ V or GND}; I_{O} = 0 \text{ A};$ supply current 2.0 20 40 μA I_{CC} ---- $V_{CC} = 6.0 V$ Cı input 3.5 pF -----capacitance

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 8.

Symbol Parameter		Conditions		nditions T _{amb} :		°C	T _{amb} = −40 °C to +85 °C		T _{amb} = −40 °C to +125 °C		Unit
				Min	Тур	Max	Min	Max	Min	Max	
t _{pd}	propagation	nA to nY; see Figure 7	[1]								
	delay	$V_{CC} = 2.0 V$		-	25	85	-	105	-	130	ns
		$V_{CC} = 4.5 V$		-	9	17	-	21	-	26	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	7	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	7	14	-	18	-	22	ns
tt	transition	Yn; see Figure 7	[2]								
	time	$V_{CC} = 2.0 V$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 V$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 V$		-	6	13	-	16	-	19	ns

Hex non-inverting HIGH-to-LOW level shifter

Voltages	are referenced	I to GND (ground = 0 V); $C_L = 50$	p⊢ unle	ess othe	erwise	specified	; for test ci	rcuit see	-igure 8.	
Symbol Parameter Conditions		Conditions	T _{an}	_{nb} = 25	°C		–40 °C 85 °C		: –40 °C ∣25 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
C _{PD}	power dissipation capacitance	$C_{L} = 50 \text{ pF}; \text{ f} = 1 \text{ MHz}; \qquad [3]$ V _I = GND to V _{CC}	-	14	-	-	-	-	-	pF

Table 7. Dynamic characteristics ... continued

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). P_{D} = $C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N$ + $\Sigma (C_{L} \times V_{CC}{}^{2} \times f_{o})$ where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

11. Waveforms

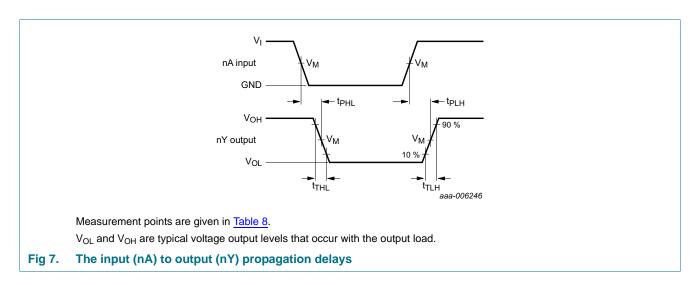


Table 8. **Measurement points**

Туре	Input	Output
	V _M	V _M
74HC4050	0.5V _{CC}	0.5V _{CC}

74HC4050

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74HC4050

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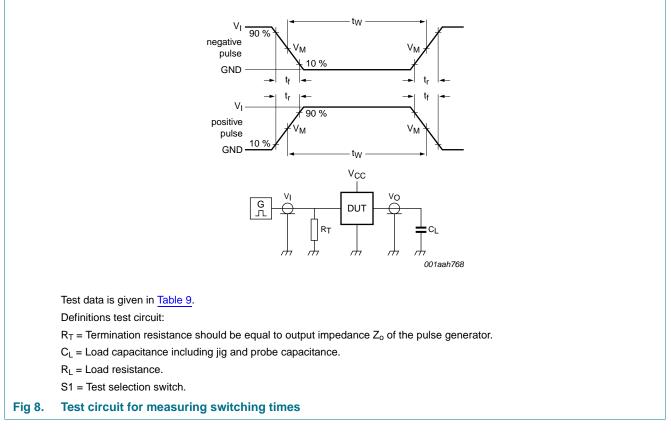


Table 9. Test data

Туре	Input I		Load	Test
	VI	t _r , t _f	CL	
74HC4050	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

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12. Package outline

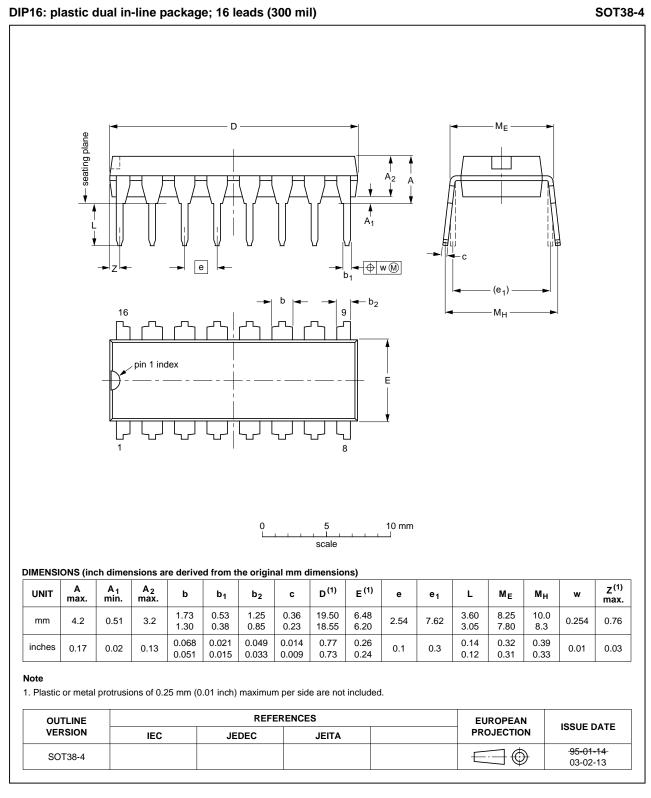


Fig 9. Package outline SOT38-4 (DIP16)

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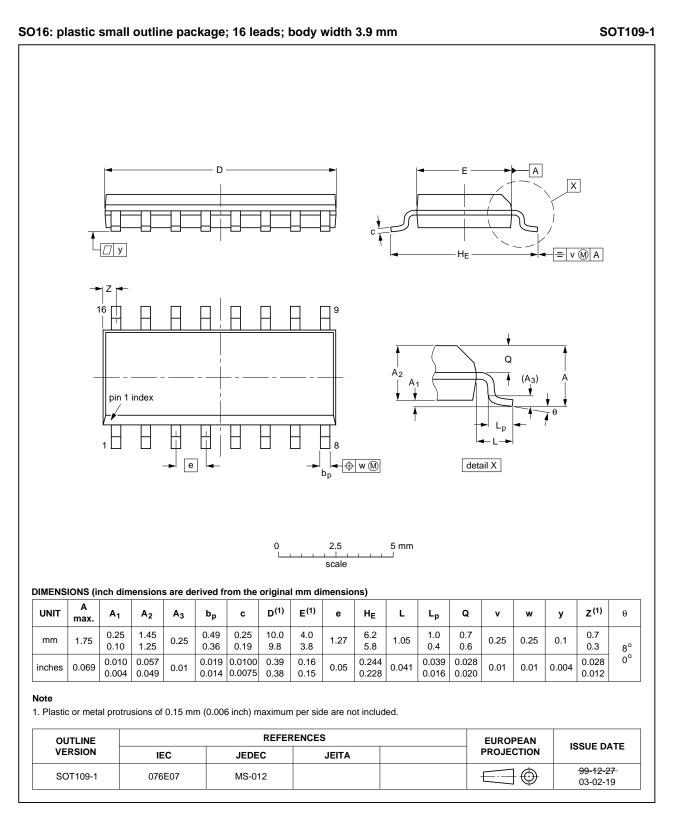


Fig 10. Package outline SOT109-1 (SO16)

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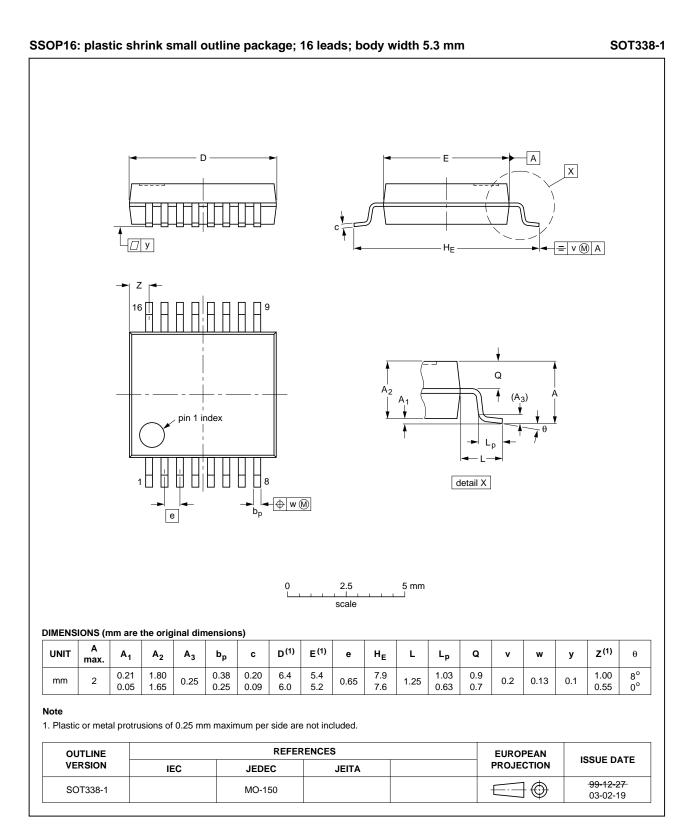


Fig 11. Package outline SOT338-1 (SSOP16)

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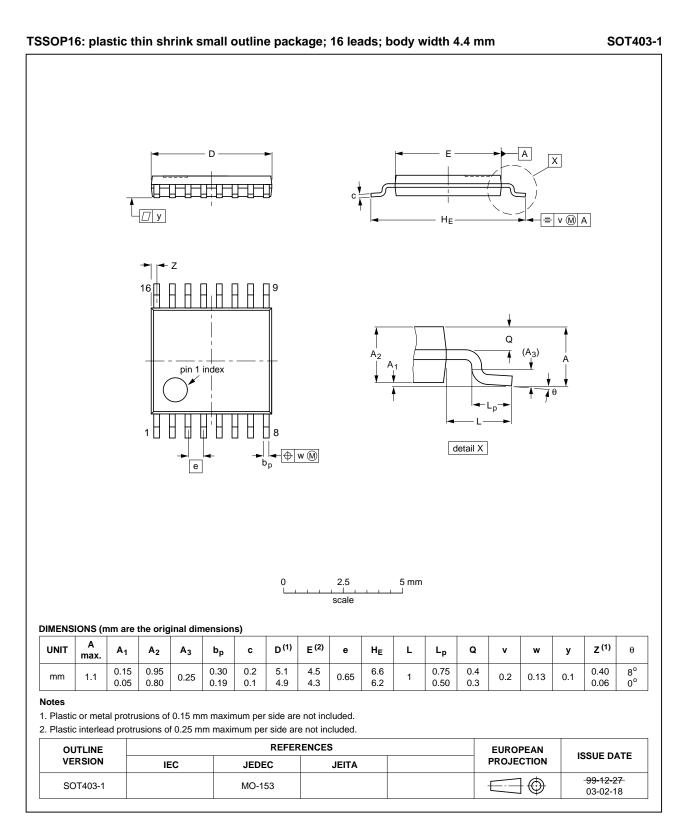


Fig 12. Package outline SOT403-1 (TSSOP16)

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13. Abbreviations

Table 10.	Abbreviations
Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC4050 v.3	20130131	Product data sheet	-	74HC4050_CNV v.2
Modifications:		t of this data sheet has b of NXP Semiconductors	•	nply with the new identity
	 Legal texts 	have been adapted to the	ne new company name	e where appropriate.
74HC4050_CNV v.2	19970826	Product specification	-	-

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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